

November 2013

FGP5N60LS 600 V, 5 A Field Stop IGBT

Features

- · High Current Capability
- Low Saturation Voltage: V_{CE(sat)} = 1.7 V @ I_C = 5 A
- High Input Impedance
- RoHS Compliant

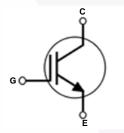
Applications

HID Ballast

General Description

Using novel field stop IGBT technology, Fairchild's new series of field stop IGBTs offer the optimum performance for HID ballast where low conduction losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage		600	V
V _{GES}	Gate to Emitter Voltage		±20	V
I _C	Collector Current	$@ T_C = 25^{\circ}C$	10	Α
	Collector Current	$@ T_C = 100^{\circ}C$	5	Α
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25°C	36	A
P _D	Maximum Power Dissipation	@ T _C = 25°C	83	W
	Maximum Power Dissipation	$@ T_C = 100^{\circ}C$	33	W
TJ	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
T _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes: 1: Repetitive test , Pulse width = 100 usec , Duty = 0.2, V_{GE} = 13.5 V

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case	-	1.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient		62.5	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGP5N60LS	FGP5N60LS	TO-220	Tube	N/A	N/A	50

Electrical Characteristics of the IGBT $T_C = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics		•	•	•	
BV _{CES}	Collector to Emitter Breakdown Voltage	$V_{GE} = 0 \text{ V}, I_{C} = 250 \mu\text{A}$	600	-	-	V
$\Delta BV_{CES} \over \Delta T_J$	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0 \text{ V, } I_{C} = 250 \mu\text{A}$	-	0.8	-	V/°C
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$	-	-	250	μΑ
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0 V$	-	-	±400	nA
On Charac	eteristics					
V _{GE(th)}	G-E Threshold Voltage	$I_C = 250 \mu A, V_{CE} = V_{GE}$	2.7	3.9	4.5	V
		I _C = 5 A, V _{GE} = 15 V	-	1.7	2.1	V
V	Collector to Emitter Saturation Voltage	$I_C = 5 \text{ A}, V_{GE} = 15 \text{ V},$ $T_C = 125^{\circ}\text{C}$	-	1.8	-	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 14 A, V _{GE} = 12 V	-	2.7	3.2	V
		I _C = 14 A, V _{GE} = 12 V, T _C = 125°C	-	3.1	-	V
Dynamic C	Characteristics				•	
C _{ies}	Input Capacitance		-	278	-	pF
C _{oes}	Output Capacitance	$V_{CE} = 30 \text{ V}, V_{GE} = 0 \text{ V},$ f = 1 MHz	-	28	-	pF
C _{res}	Reverse Transfer Capacitance		-	11	-	pF
Switching	Characteristics		·			
t _{d(on)}	Turn-On Delay Time		_	4.3	_	ns
t _r	Rise Time		-	1.6	-	ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 400 \text{ V}, I_{C} = 5 \text{ A},$	-	36	-	ns
t _f	Fall Time	$R_G = 10 \Omega$, $V_{GE} = 15 V$,	-	118	-	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 25°C	-	38	-	μJ
E _{off}	Turn-Off Switching Loss		-	130	-	μJ
E _{ts}	Total Switching Loss		-	168	-	μJ
t _{d(on)}	Turn-On Delay Time		-	4.1	-	ns
t _r	Rise Time		-	1.8	- //	ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 400 \text{ V}, I_{C} = 5 \text{ A},$	-	37	-	ns
t _f	Fall Time	$R_G = 10 \Omega$, $V_{GE} = 15 V$,	-	150	-	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 125°C	-	80	-	μJ
E _{off}	Turn-Off Switching Loss		-	168	-	μJ
E _{ts}	Total Switching Loss		-	248	-	μJ
Qg	Total Gate Charge		-	18.3	-	nC
Q _{ge}	Gate to Emitter Charge	$V_{CE} = 400 \text{ V}, I_{C} = 5 \text{ A},$	-	1.6	-	nC
Q _{gc}	Gate to Collector Charge	V _{GE} = 15 V	-	7.9	-	nC

Figure 1. Typical Output Characteristics

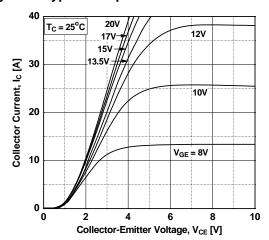


Figure 3. Typical Saturation Voltage Characteristics

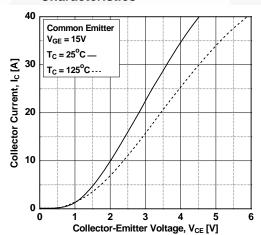


Figure 5. Saturation Voltage vs. Case
Temperature at Variant Current Level

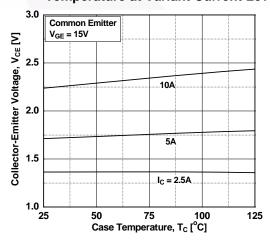


Figure 2. Typical Output Characteristics

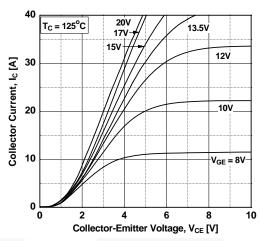


Figure 4. Transfer Characteristics

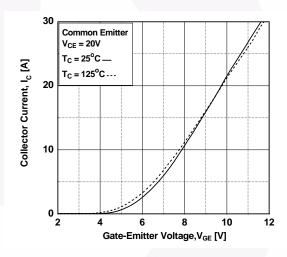


Figure 6. Saturation Voltage vs. V_{GE}

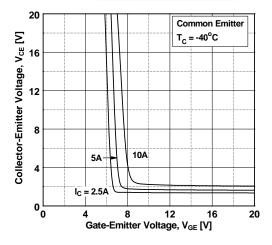


Figure 7. Saturation Voltage vs. V_{GE}

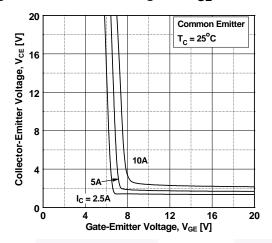


Figure 9. Capacitance Characteristics

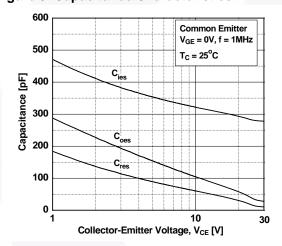


Figure 11. SOA Characteristics

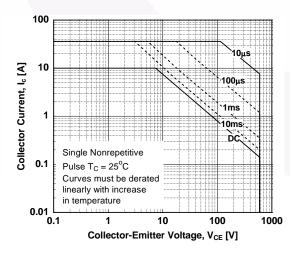


Figure 8. Saturation Voltage vs. V_{GE}

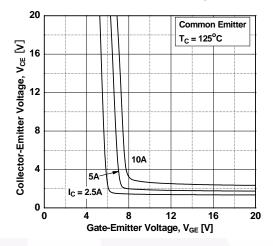


Figure 10. Gate charge Characteristics

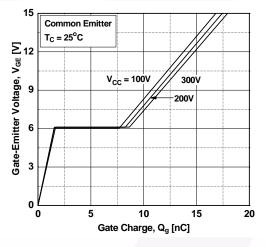


Figure 12. Turn-on Characteristics vs.
Gate Resistance

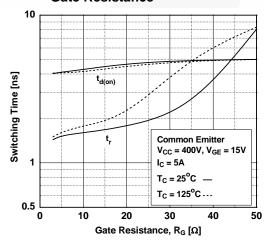


Figure 13. Turn-off Characteristics vs.
Gate Resistance

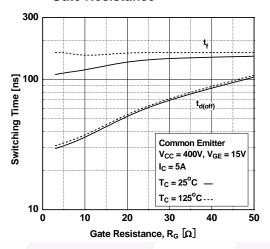


Figure 15. Turn-off Characteristics vs. Collector Current

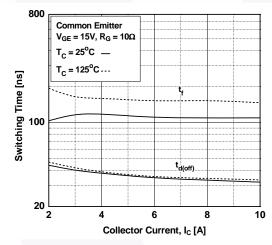


Figure 17. Switching Loss vs. Collector Current

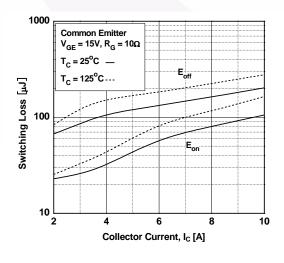


Figure 14. Turn-on Characteristics vs. Collector Current

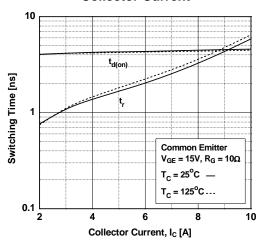


Figure 16. Switching Loss vs. Gate Resistance

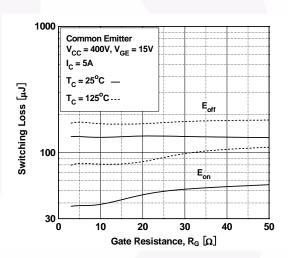


Figure 18. Turn off Switching SOA Characteristics

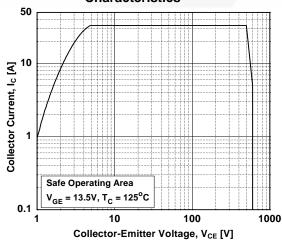
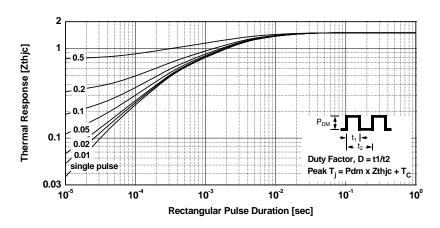


Figure 19.Transient Thermal Impedance of IGBT



Mechanical Dimensions

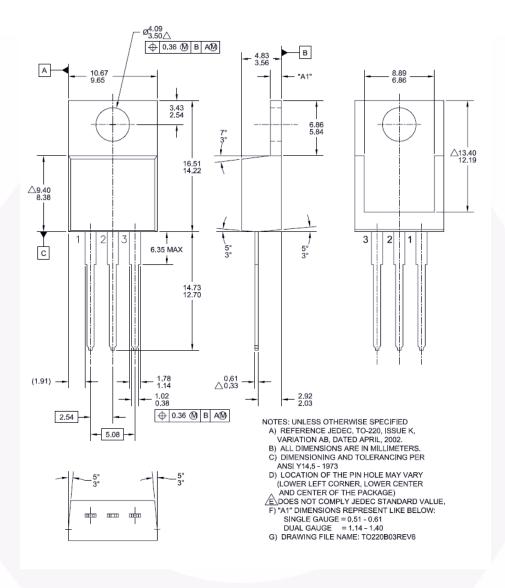


Figure 20. TO-220 3L - TO-220, MOLDED, 3LEAD, JEDEC VARIATION AB

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